PNP/NPN Epitaxial Planar Silicon Transistors



2SA1518/2SC3912

Switching Applications (With Bias Resistance)

Application

• Switching circuits, inverters circuits, inferface circuits, driver circuits.

Features

- · On-chip bias resistance : R1=10k Ω , R2=10k Ω .
- · Small-sized package : CP.
- \cdot Large current capacity : I_C=500mA.

Package Dimensions

unit:mm



():2SA1518

Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CBO}		(–)50	V
Collector-to-Emitter Voltage	VCEO		(–)50	V
Emitter-to-Base Voltage	VEBO		(–)10	V
Collector Current	ΙC		(–)500	mA
Peak Collector Current	I _{CP}		(–)800	mA
Collector Dissipation	PC		200	mW
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Collector Cutoff Current	ICBO	V _{CB} =(-)40V, I _E =0			(–)0.1	μA
	ICEO	V _{CE} =(-)40V, IB=0			(–)0.5	μA
Emitter Cutoff Current	IEBO	V _{EB} =(-)5V, I _C =0	(–)195	(–)250	(–)360	μA
DC Current Gain	h _{FE}	V _{CE} =(-)5V, I _C =(-)10mA	50*			
Gain-Bandwidth Product	fT	V _{CE} =(-)10V, I _C =(-)5mA		250		MHz
				(200)		MHz
Output Capacitance	Cob	V _{CB} =(-)10V, f=1MHz		3.7		pF
				(5.5)		pF
Collector-to-Emitter Saturation Voltage	V _{CE(sat)}	I _C =(-)20mA, I _B =(-)1mA		(–)0.1	(–)0.3	V
Collector-to-Base Breakdown Voltage	V(BR)CBO	I _C =(-)10µA, I _E =0	(–)50			V
Collector-to-Emitter Breakdown Voltage	V _(BR) CEO	I _C =(–)100μA, R _{BE} =∞	(–)50			V
Input OFF-State Voltage	V _{I(off)}	V _{CE} =(-)5V, I _C =(-)100μA	(-)0.8	(–)1.1	(–)1.5	V
Input ON-State Voltage	V _{I(on)}	V _{CE} =(-)0.2V, I _C =(-)10mA	()1.0	(–)2.0	(–)4.0	V
Input Resistance	R1		7	10	13	kΩ
Resistance Ratio	R1/R2		0.9	1.0	1.1	

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Electrical Connection



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